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Education background

Ph.D Degree: State Key Laboratory of Solid State Microstructures, Department of Physics, Nanjing University, 2003.9-2006.7

M.Sc. Degree: Department of Physics, Yunnan University, and Joint Laboratory of Nonlinear Complex Systems, 2000.9-2003.7

B. Sc. Degree: Department of Physics, Yunnan University, undergraduate | 1995.9-2000.7

Work experience

State Key Laboratory of Semiconductor Superlattices, Institute of Semiconductors, Chinese Academy of Sciences, Associate Researcher | 2011.9-present

University of Hong Kong Department of Physics, Visiting Scholar | 2012.12-2013.2

Department of Physics, University of Hong Kong, Postdoctoral | 2009.8-2011.8

Purdue University, USA Department of Physics, Postdoctor | 2008.4-2009.8

Chinese Academy of Sciences Institute of Physics, Postdoctoral | 2006.7-2008.6

Department of Physics, Hong Kong University of Science and Technology, Visiting Scholar | 2007.10-2007.12

Research Field: Theory and Computation of Condensed States

Publications

Spin-filtered and spatially distinguishable crossed Andreev reflection in a silicene-superconductor junction

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Topological insulator-graphene junction for spin transport

H. Li, H. B. Zhang, J. M. Shao, Y. Y. Zhang, D. X. Yao and G. W. Yang. Applied Physics Letters: 2012,101,243102

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Band structures and transport properties of zigzag graphene nanoribbons with antidot arrays

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Impurity-induced bound states in iron-based superconductors with s-wave cos kx ·cos ky pairing symmetry

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SCI Citations: >500